




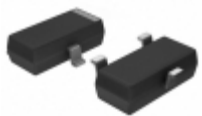


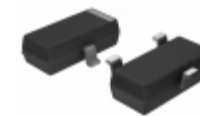
	<h2 style="color: red;">FJV3111RMTF</h2>	
	<b>Hersteller-Teilenummer:</b>	FJV3111RMTF
	<b>Hersteller / Marke:</b>	AMI Semiconductor / ON Semiconductor
	<b>Teil der Beschreibung:</b>	TRANS PREBIAS NPN 200MW SOT23-3
Image may be representation. See specs for product details.	<b>Datenblätter:</b>	<a href="#">1.FJV3111RMTF.pdf</a> <a href="#">2.FJV3111RMTF.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 84000 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS

### Spezifikationen

Teilenummer	FJV3111RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	84000 pcs Stock
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) NPN - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	40V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 1mA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	100 @ 1mA, 5V
Frequenz - Übergang	250MHz
Verpackung	Tape & Reel (TR)
Widerstand - Basis (R1)	22 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FJV3111RMTF ist neu im Original, Suche FJV3111RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3111RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3111RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>FJV3111RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3112RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3113RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3109R</b> FAIRCHI FJV3109R FAIRCHI</p>
 <p><b>FJV3110RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3109RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3112RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3113RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>

### heiße Teile

Mehr

⊗ FJV1845UMTF	↔ FJV1845UMTF	⇒ FJV3101RLIMTF	D FJV3101RMTF	⇒ FJV3101RMTF
⊣ FJV3102RMTF	⊗ FJV3102RMTF	D FJV3103RMTF	⇒ FJV3103RMTF	⇒ FJV3104RMTF
⊗ FJV3104RMTF	⊣ FJV3105RMTF	⊗ FJV3105RMTF	↔ FJV3106RMTF	⇒ FJV3106RMTF
D FJV3107RMTF	⊗ FJV3107RMTF	⊣ FJV3108RMTF	⊗ FJV3108RMTF	⇒ FJV3109R
⇒ FJV3109RMTF	↔ FJV3109RMTF	⊗ FJV3110RMTF	⊣ FJV3110RMTF	⇒ FJV3111RMTF
↔ FJV3112RMTF	⇒ FJV3112RMTF	D FJV3113RMTF	⊗ FJV3113RMTF	⊣ FJV3114RMTF
⊗ FJV3114RMTF	D FJV3115RMTF	⇒ FJV3115RMTF	↔ FJV4101RMTF	⇒ FJV4101RMTF
⊣ FJV4102RLIMTF	⊗ FJV4102RMTF	↔ FJV4102RMTF	⇒ FJV4103RMTF	⇒ FJV4103RMTF
⊗ FJV4104RMTF	⊣ FJV4104RMTF	⊗ FJV4105RMTF	D FJV4105RMTF	⇒ FJV4106RMTF
↔ FJV4106RMTF	⊗ FJV4107RMTF	⊣ FJV4107RMTF	⊗ FJV4108RMTF	⇒ FJV4108RMTF

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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